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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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# FX30KMJ-3

High-Speed Switching Use Pch Power MOS FET

REJ03G1448-0200

(Previous: MEJ02G0291-0101)

Rev.2.00 Aug 07, 2006

### **Features**

• Drive voltage : 4 V

 $\bullet \quad V_{DSS}:-150 \ V$ 

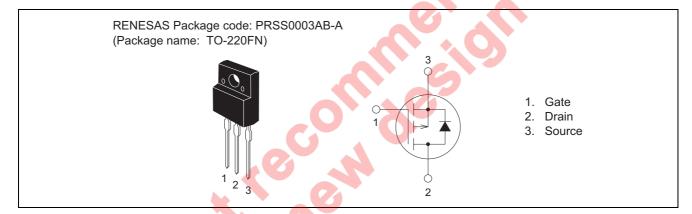
•  $r_{DS(ON) (max)}$ : 100 m $\Omega$ 

•  $I_D: -30 A$ 

• Integrated Fast Recovery Diode (TYP.): 100 ns

• Viso: 2000 V

### **Outline**



# **Applications**

Motor control, Lamp control, Solenoid control, DC-DC converters, etc.

# **Maximum Ratings**

 $(Tc = 25^{\circ}C)$ 

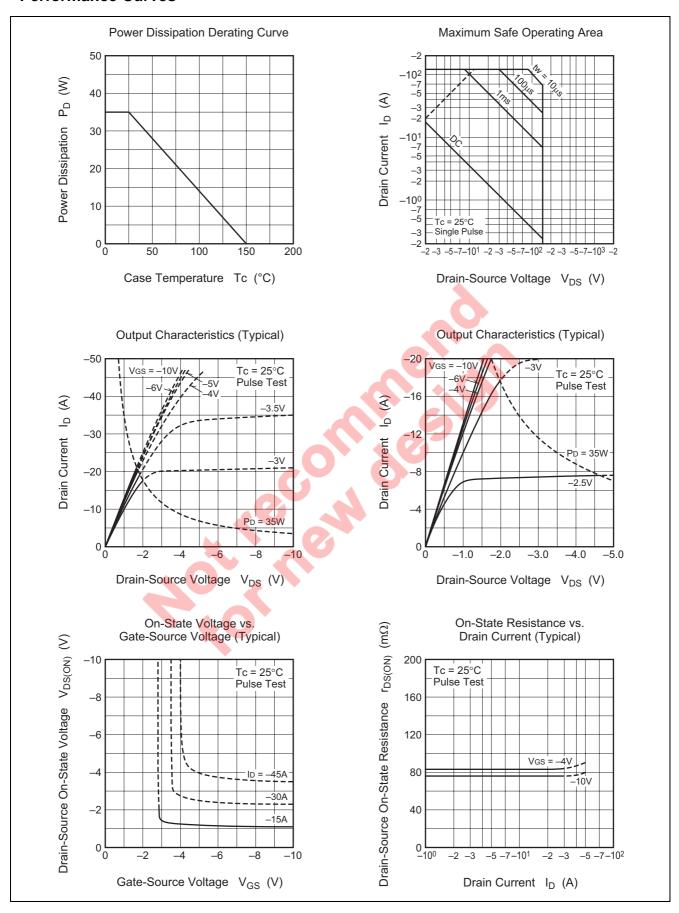
| Parameter                        | Symbol          | Ratings      | Unit | Conditions                           |
|----------------------------------|-----------------|--------------|------|--------------------------------------|
| Drain-source voltage             | $V_{DSS}$       | -150         | V    | $V_{GS} = 0 V$                       |
| Gate-source voltage              | $V_{GSS}$       | ±20          | V    | $V_{DS} = 0 V$                       |
| Drain current                    | I <sub>D</sub>  | -30          | Α    |                                      |
| Drain current (Pulsed)           | I <sub>DM</sub> | -120         | Α    |                                      |
| Avalanche drain current (Pulsed) | I <sub>DA</sub> | -30          | Α    | L = 30 μH                            |
| Source current                   | Is              | -30          | Α    |                                      |
| Source current (Pulsed)          | I <sub>SM</sub> | -120         | А    |                                      |
| Maximum power dissipation        | P <sub>D</sub>  | 35           | W    |                                      |
| Channel temperature              | Tch             | - 55 to +150 | °C   |                                      |
| Storage temperature              | Tstg            | - 55 to +150 | °C   |                                      |
| Isolation voltage                | Viso            | 2000         | V    | AC for 1 minute,<br>Terminal to case |
| Mass                             | _               | 2.0          | g    | Typical value                        |

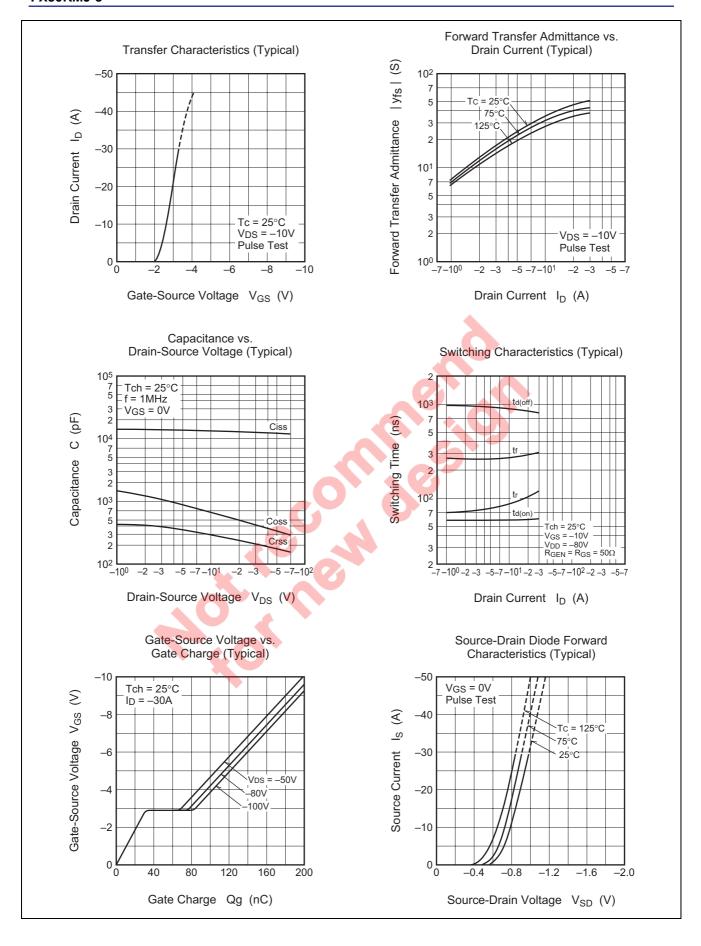
# **Electrical Characteristics**

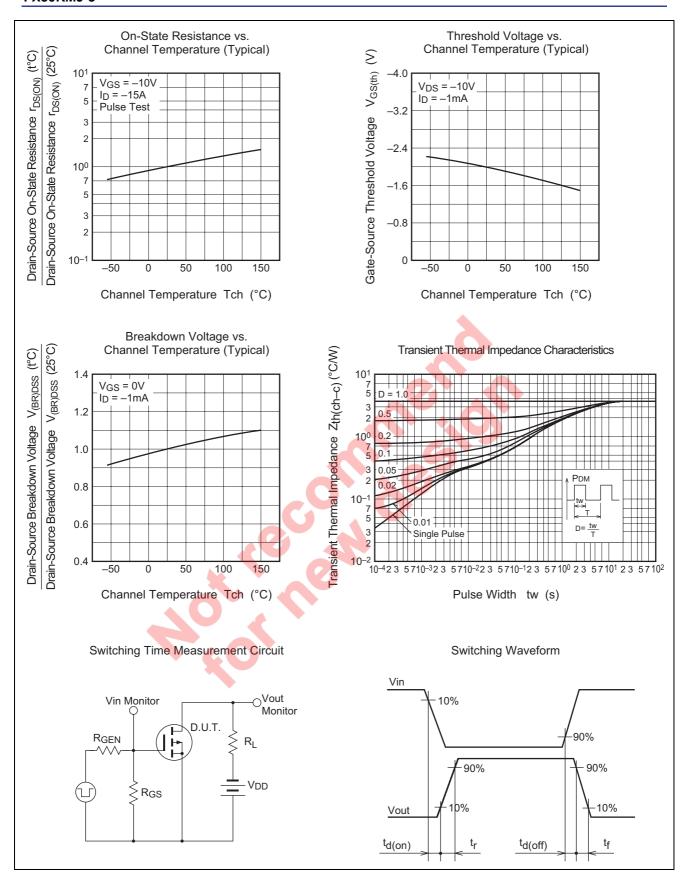
 $(Tch = 25^{\circ}C)$ 

| Parameter  | Symbol                | Min  | Тур   | Max   | Unit | Test Conditions  |  |
|--|-----------------------|------|-------|-------|------|--|--|
| Drain-source breakdown voltage   | V <sub>(BR)DSS</sub>  | -150 | _     | _     | V    | $I_D = -1 \text{ mA}, V_{GS} = 0 \text{ V}$                    |  |
| Gate-source leakage current  | I <sub>GSS</sub>      | _    | _     | ±0.1  | μΑ   | $V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$              |  |
| Drain-source leakage current   | I <sub>DSS</sub>      | _    | _     | -0.1  | mA   | $V_{DS} = -150 \text{ V}, V_{GS} = 0 \text{ V}$                |  |
| Gate-source threshold voltage  | V <sub>GS(th)</sub>   | -1.3 | -1.8  | -2.3  | V    | $I_D = -1 \text{ mA}, V_{DS} = -10 \text{ V}$                  |  |
| Drain-source on-state resistance   | r <sub>DS(ON)</sub>   | _    | 78    | 100   | mΩ   | $I_D = -15 \text{ A}, V_{GS} = -10 \text{ V}$                  |  |
| Drain-source on-state resistance   | r <sub>DS(ON)</sub>   | _    | 85    | 111   | mΩ   | $I_D = -15 \text{ A}, V_{GS} = -4 \text{ V}$                   |  |
| Drain-source on-state voltage  | $V_{DS(ON)}$          | _    | -1.17 | -1.50 | V    | $I_D = -15 \text{ A}, V_{GS} = -10 \text{ V}$                  |  |
| Forward transfer admittance  | y <sub>fs</sub>       | _    | 41.3  | _     | S    | $I_D = -15 \text{ A}, V_{DS} = -10 \text{ V}$                  |  |
| Input capacitance  | Ciss                  | _    | 11430 | _     | pF   | $V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V},$                |  |
| Output capacitance   | Coss                  | _    | 674   | _     | pF   | f = 1MHz   |  |
| Reverse transfer capacitance   | Crss                  | _    | 320   | _     | pF   |  |  |
| Turn-on delay time   | t <sub>d(on)</sub>    | _    | 61    | _     | ns   | $V_{DD} = -80 \text{ V}, I_D = -15 \text{ A},$                 |  |
| Rise time  | t <sub>r</sub>        | _    | 99    | _     | ns   | $V_{GS} = -10 \text{ V},$                                      |  |
| Turn-off delay time  | t <sub>d(off)</sub>   | _    | 878   | _     | ns   | $R_{GEN} = R_{GS} = 50 \Omega$                                 |  |
| Fall time  | t <sub>f</sub>        | _    | 330   | - (   | ns   |  |  |
| Source-drain voltage   | $V_{SD}$              | _    | -1.0  | -1.5  | V    | I <sub>S</sub> = -15 A, V <sub>GS</sub> = 0 V                  |  |
| Thermal resistance   | R <sub>th(ch-c)</sub> | _    | _     | 3.57  | °C/W | Channel to case  |  |
| Reverse recovery time  | t <sub>rr</sub>       | _    | 100   | (4)   | ns   | $I_S = -30 \text{ A}, d_{is}/d_t = 100 \text{ A}/\mu \text{S}$ |  |
| Thermal resistance $R_{th(ch\cdot c)}$ — $-$ 3.57 °C/W Channel to case $R_{tr}$ — $100$ — $R_{tr}$ — $100$ — $R_{tr}$ — $R_{$ |                       |      |       |       |      |  |  |
| 1-40   |                       |      |       |       |      |  |  |

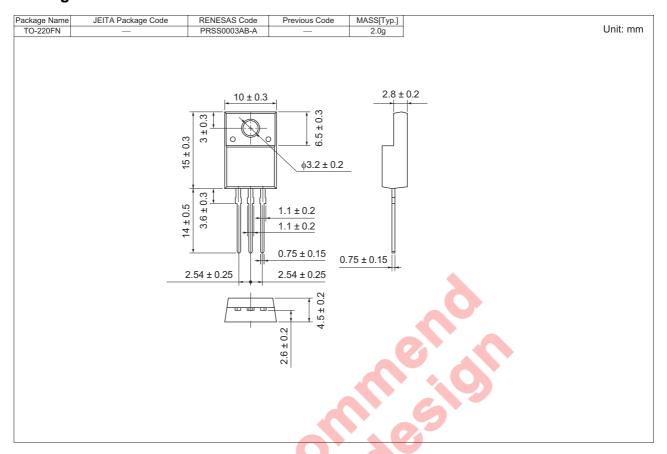
# **Performance Curves**







# **Package Dimensions**



# **Order Code**

| Lead form     | Lead form Standard packing |    | Standard order code           | Standard order code example |  |
|---------------|----------------------------|----|-------------------------------|-----------------------------|--|
| Straight type | Plastic Magazine (Tube)    | 50 | Type name                     | FX30KMJ-3                   |  |
| Lead form     | Plastic Magazine (Tube)    | 50 | Type name – Lead forming code | FX30KMJ-3-A8                |  |

Note: Please confirm the specification about the shipping in detail.

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